

Initial Wetting System - Introduction

The initial wetting of a lum in um has a significant influence on the efficiency of the evaporation process .

The "Initial Wetting System " is characterized by an improvement of the initial wetting of a lum in um .

Initial Wetting System – Status Quo

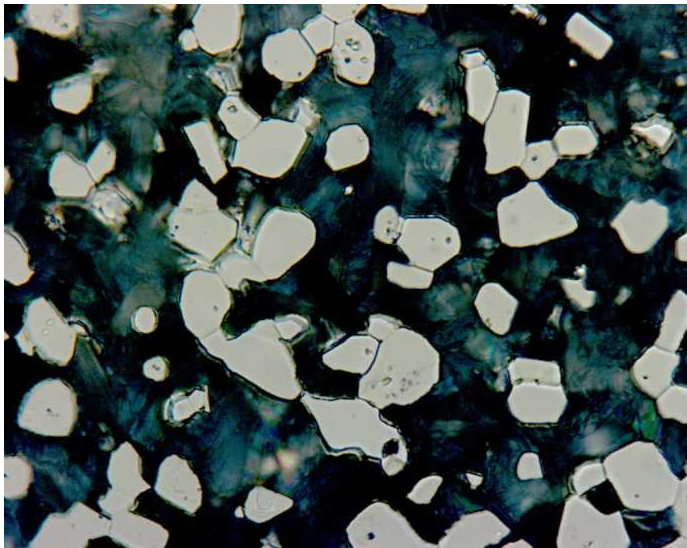
Break in difficulties of unused evaporators regarding wetability of aluminum

Reason for that difficulties:

- The unused evaporator consists of approx. 65 Vol% of Boron-Nitride (BN) which is hard to wet by aluminum.
- Boron-Nitride (BN) is “aluminumophobic” because of the anisotropic crystal structure.

Structure of IMC-Evaporators

65 Vol% of Boron-Nitride (BN) which is hard to wet by a liquid metal.

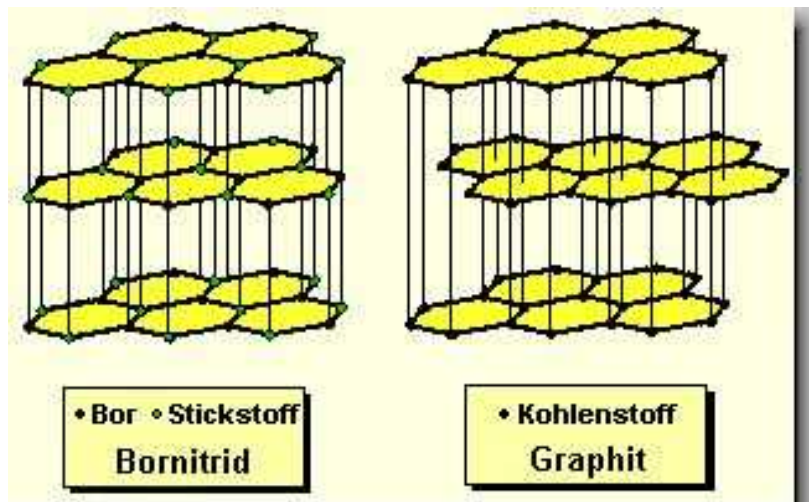


Dark areas = BN

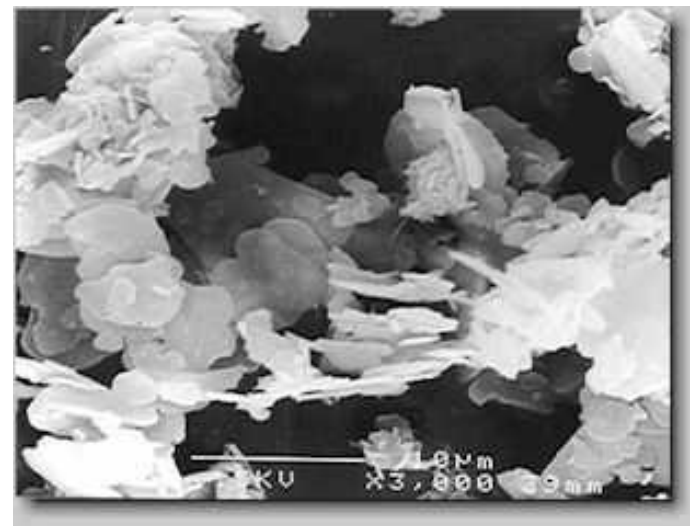
Light-colored areas = TB_2

Etched Surface of an IMC-Evaporator Boat

Crystal Structure of Boron-Nitride

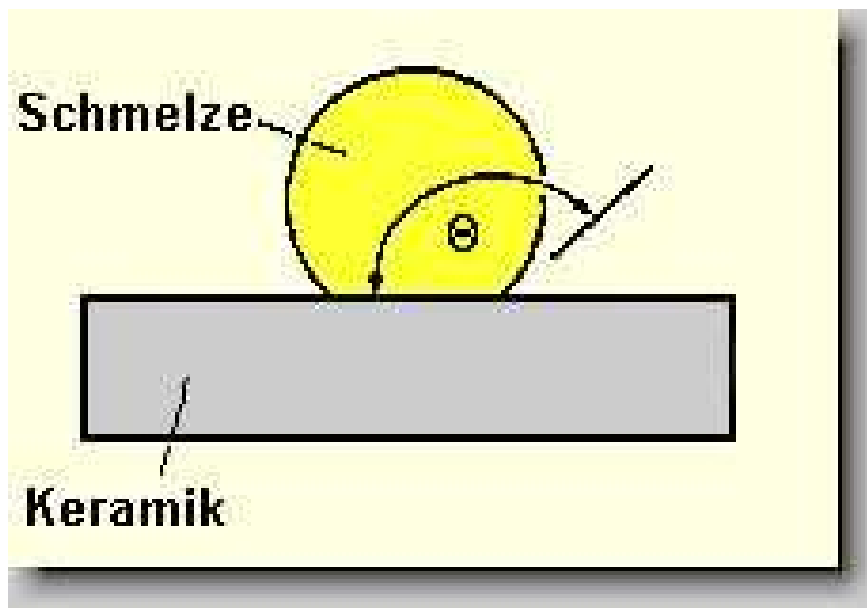


Crystal structure of fBN (Bornitrid) – schematically



Plates of fBN ; SEM -analysis (3000x; SE)

Wetability in General

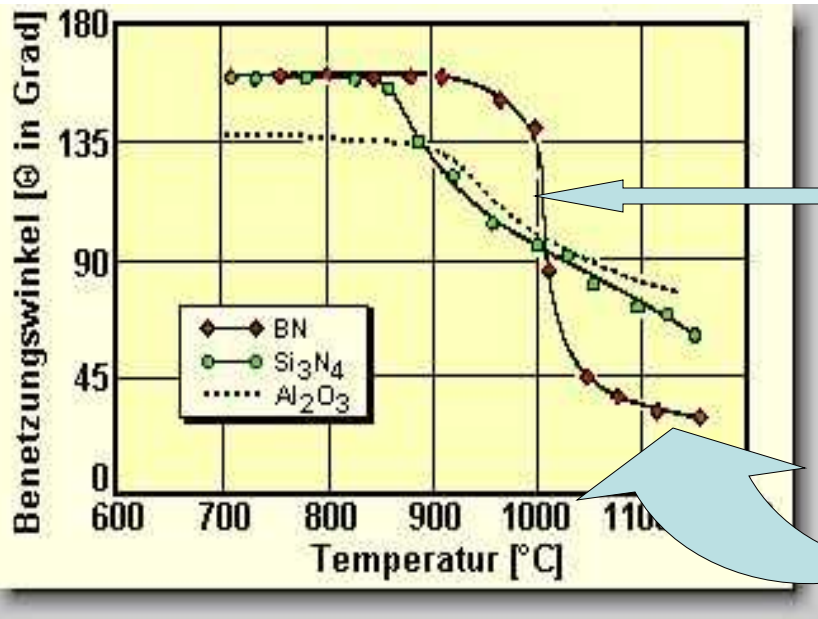


Comment:
Wetting angle of contact $\Theta > 90^\circ$:
bad wetability

Wetting angle of contact $\Theta < 90^\circ$:
good wetability

Definition of the „wetting angle of contact Θ ” on ceramic substrates

Wetability in General



Comments:

At 1000°C BN reacts with Al building AlN.

Therefore at >1000°C you can see the good wetability of Al on AlN.

Wetability of alumina on BN (AlN), Si₃N₄, Al₂O₃ surfaces in dependence of the temperature

Vapour Pressure and Evaporation Temperature

Vapor pressure	Evaporation temperature of Al in °C
$1,33 \cdot 10^{-4}$ mbar	920 °C
$1,33 \cdot 10^{-2}$ mbar	1140 °C

Evaporation temperature of Al in dependence of the vapour pressure

Comments:

You see that the liquid Al evaporates before building up the good wettable AN at 1000 °C .
Therefore the aluminium can be only partially distributed onto the evaporator surface .

Some Questions

Why does evaporator boats consist of BN?

BN provide:

- A very good thermal shock resistance
- The right specific resistivity (electrical insulator)
- A good machinable material

What's the reason for good wetting of Al after a certain time of continuously Al-feed?

BN get decomposed on the hotter, not wetted
evaporator surface area during metallization

The remaining TB_2 of the evaporator boat material is a wetting catalyzer.

Initial Wetting System - Theoretical Background

A) Components of the Initial Wetting System

“Initial Wetting System” = a combination of aluminum and a wetting agent

Compounds of the wetting agent: Ti and Si.

Initial Wetting System - Theoretical Background

B) First Heating Up of the Initial Wetting System

$T = 700-1000\text{ }^{\circ}\text{C}$

The wetting agent reduces the “wetting angle of contact” of the Al.
This effect helps to distribute the liquid Al.

$T = \text{approx. } 1000\text{ }^{\circ}\text{C}$

Al reacts with the BN of evaporator surface building AlN.
Al wets AlN well.

$T > 1000\text{ }^{\circ}\text{C}$

The residual Al evaporates.

There remains a thin AlN-layer which covers almost the whole cavity surface of the evaporator.

Initial Wetting System - Theoretical Background

C) Continuous A/W wire Feed

The thin A/N-layer on the evaporator surface is wetted by A much better than BN

The wetting area is bigger than usual.

The wetting is more homogeneous than usual.

By proper running conditions the good wetting can be maintained from the beginning to the end of the evaporator boat life.

Initial Wetting System – Possible Concern

A) Toxicity

The wetting agents consist of a compound of Titanium and Silicon.

=> Both elements are not critical with regard to food contact.

Initial Wetting System – Possible Concern

B) Quantities – A Calculation Example

In a 99,8 % Al-wire (99,8%) can be found Titanium and Silicon as impurities as follows:

Ti= approx. 0,02%

Si= approx. 0,15%

Sintec uses only a very small quantity of that Titanium-Silicon-compound:

1-2 mg/cm² = approx. 20-60 mg/boat

=> 15-40 g Al-wire (99,8%) does contain the same quantity of Si as the WS

Initial Wetting System – Possible Concern

C) Analysis

No Titanium and Silicon increase in the metallized film could be detected.

The Ti and Si possibly remains on to the shutter before starting metallization

Initial Wetting System – Visualization

- a) Video 1: Initial wetting without “Initial Wetting system ”
- b) Video 2: Initial wetting with “Initial Wetting System ”